

# 8.0V to 35V, 1.5A 1ch Buck Converter with Integrated FET

# BD9870FPS

#### **General Description**

The BD9870FPS is a single-channel step-down switching regulator integrated with a P-Channel MOSFET capable of PWM operation at 900 kHz. It employs the use of smaller coil and circuitry to eliminate the need for external compensation. The circuitry consists only of a diode, coil and ceramic capacitor thus reducing the board size significantly.

#### Features

- Built-in P-Channel MOSFET for High Efficiency
- Adjustable Output Voltage Via External Resistors
- Soft-Start Time: 5ms (Fixed)
- Built-In Over-Current Protection and Thermal Shutdown Circuits
- ON/OFF Control Via STBY Pin
- Ceramic Output Capacitor Compatibility

#### Applications

TVs, Printers, DVD Players, Projectors, Gaming Devices, PCs, Car Audio/Navigation Systems, ETCs, Communication Equipment, AV Products, Office Equipment, Industrial Devices, and more.

#### **Key Specifications**

- Input Voltage Range: 8.0V to 35.0V
- Output Voltage Range:1.0V to0.8Vx(Vcc-louTxRoN)V
  Output Current: 1.5A(Max)
- Output Current: 1.5A(Max)
  Switching Frequency: 900kHz(Typ)
- Output ON-Resistance: 1.0Ω(Typ)
- Standby Current: 0μA (Typ)
- Operating Temperature Range: -40°C to +85°C

Package

W(Typ) x D(Typ) x H(Max)



# **Typical Application Circuit**

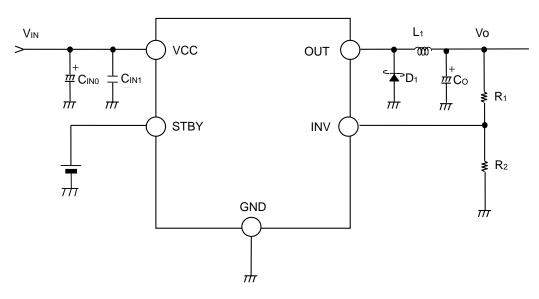


Figure 1. Typical Application Circuit

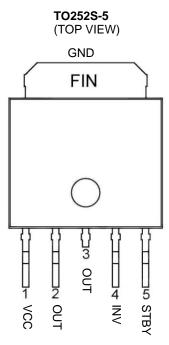


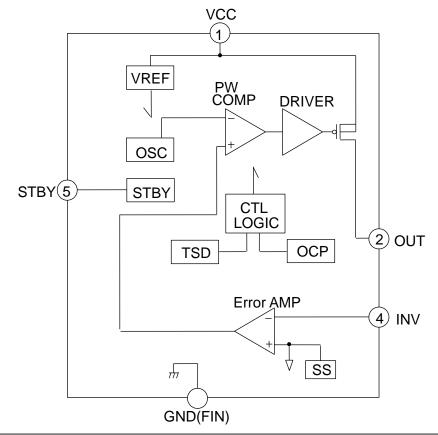
Figure 2. Pin Configuration

# Pin Description

Pin No.	Pin Name	Function	
1	VCC	Input power supply pin	
2	OUT	Internal Pch FET drain pin	
3 <sup>(Note 1)</sup>	OUT	Internal Pch FET drain pin	
FIN	GND	Ground	
4	INV	Output voltage feedback pin	
5	STBY	ON/OFF control pin	

(Note 1) Normally OPEN

# **Block Diagram**



# Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Unit
Supply Voltage (VCC-GND)	Vcc	36	V
STBY-GND	V <sub>STBY</sub>	36	V
OUT-GND	Vout	36	V
INV-GND	VINV	5	V
Maximum Switching Current	Іоит	1.5 <sup>(Note 1)</sup>	А
Power Dissipation	Pd	0.8 (Note 2)	W
Operating Temperature	Topr	-40 to +85	°C
Storage Temperature	Tstg	-55 to +150	°C

(Note 1) Do not exceed Pd, ASO, and Tjmax=150°C (Note 2) Derate by 6.4mW/°C when operating above Ta=25°C

**Caution:** Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

# Recommended Operating Conditions (Ta=-40°C to +85°C)

Deremeter	Symphol	Li	Unit		
Parameter	Symbol	Min	Max	Unit	
Input Voltage	Vcc	8.0	35.0	V	
Output Voltage	V <sub>OUT</sub>	1.0	0.8 x (V <sub>CC</sub> -I <sub>OUT</sub> x Ron)	V	

# **Electrical Characteristics**

(Unless otherwise specified, Ta=25°C, Vcc=12V, Vout=5V, VstBy=3V)

Parameter		Symbol Limit		Linit	Conditions		
		Symbol	Min	Тур	Max	Unit	Conditions
Output ON-Resistance		Ron	-	1.0	1.5	Ω	
Efficiency		η	80	88	-	%	I <sub>OUT</sub> =0.5A
Switching Frequency		fosc	810	900	990	kHz	
Load Regulation			-	5	40	mV	V <sub>cc</sub> =20V, I <sub>OUT</sub> =0.5A to 1.5A
Line Regulation		$\Delta V_{OUTLINE}$	-	5	25	mV	V <sub>CC</sub> =10V to 30V, I <sub>OUT</sub> =1.0A
Over-Current Protection Limit		IOCP	1.6	-	-	Α	
INV Pin Threshold Voltage		VINV	0.99	1.00	1.01	V	
INV Pin Input Current		linv	-	1	2	μA	V <sub>INV</sub> =1.0V
STBY Pin Threshold	ON	VSTBYON	2.0	-	36	V	
Voltage	OFF	VSTBYOFF	-0.3	-	+0.3	V	
STBY Pin Input Current		ISTBY	5	15	30	μA	V <sub>STBY</sub> =3V
Circuit Current		lcc	-	5	12	mA	V <sub>INV</sub> =2V
Stand-by Current		Ist	-	0	5	μA	V <sub>STBY</sub> =0V
Soft-Start Time		tss	1	4	10	ms	

# **Typical Performance Curves**

(Unless otherwise specified, Ta=25°C,V<sub>CC</sub>=12V,V<sub>OUT</sub>=5V, V<sub>STBY</sub>=3V)

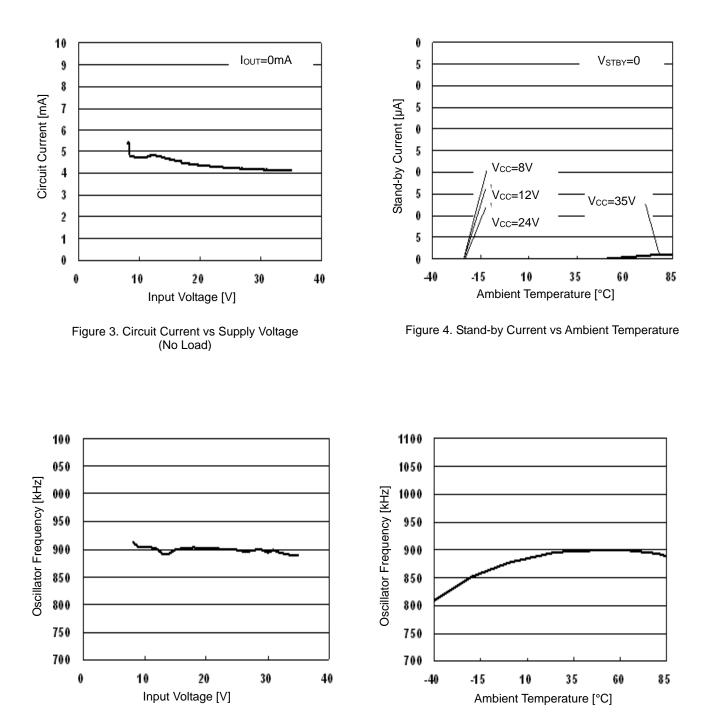


Figure 5. Oscillator Frequency vs Supply Voltage

Figure 6. Oscillator Frequency vs Ambient Temperature

# **Typical Performance Curves - continued**

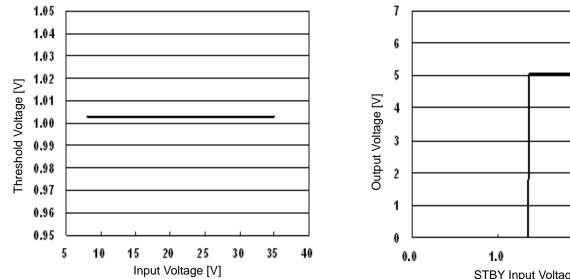
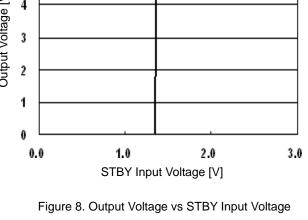


Figure 7. Error Amp Threshold Voltage vs Supply Voltage



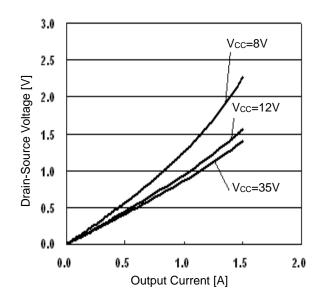


Figure 9. Driver Drain-Source Voltage vs Output Current

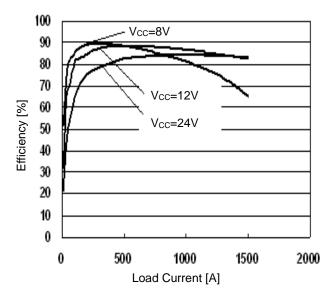
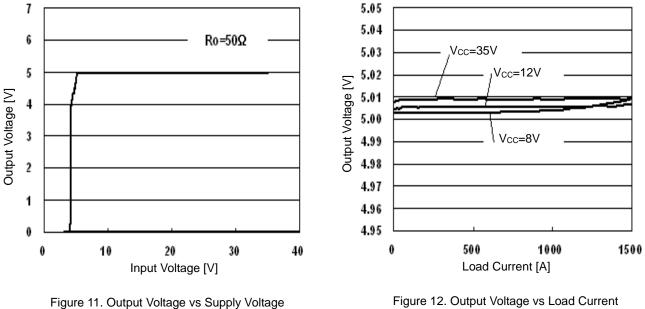


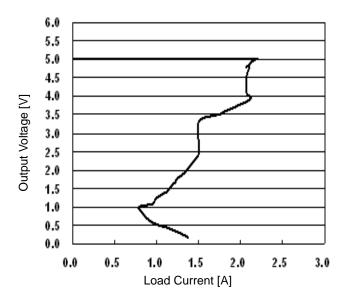
Figure 10. Efficiency vs Load Current

# **Typical Performance Curves - continued**











# **Typical Waveforms**

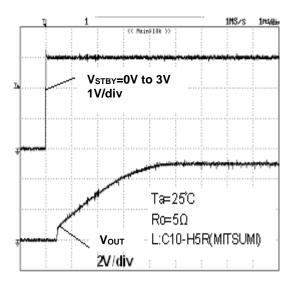


Figure 14. Output Start-up Characteristics

# **Application Information**

#### 1. Block Function Explanations

(1) VREF

This block generates a temperature-independent regulated voltage coming from the VCC input.

(2) OSC

This block generates a triangular wave with an oscillation frequency of 900kHz set by the internal resistors and capacitors. The output of this block goes to the PWM comparator.

(3) Error AMP

This block monitors the output voltage through a voltage divider network and compares it with an internal reference voltage. The output of this block is the amplified difference between the sampled output voltage and the reference.

(4) PWM COMP

This block converts the Error AMP output to PWM pulses going to the Driver block.

(5) DRIVER

This push-pull FET driver accepts PWM input pulses from PWM COMP block and drives the internal P-Channel MOSFET.

(6) STBY

ON/OFF operation of the IC is controlled via the STBY pin. The output is ON when STBY is High.

(7) Thermal Shutdown (TSD)

This circuit protects the IC against thermal runaway and damage due to excessive heat. A thermal sensor detects the junction temperature and switches the output OFF once the temperature exceeds its threshold value at 175°C. It has a built-in 15°C hysteresis to prevent malfunctions due to temperature fluctuations.

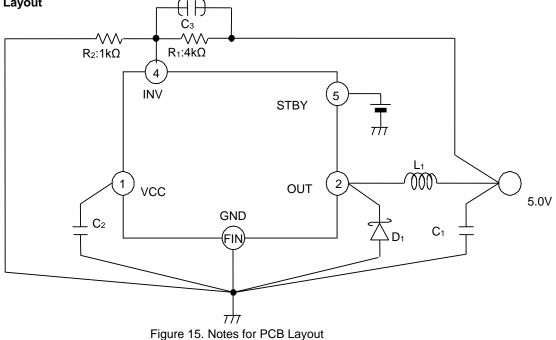
(8) Over-Current Protection (OCP)

The OCP circuit detects the voltage difference between VCC and OUT by measuring the current through the internal P-Channel MOSFET. It switches the output OFF once the voltage reaches the threshold value. The OCP block is a self-recovery type (not latch).

(9) Soft-Start (SS)

This block controls soft start operations. The internal capacitor begins charging at start up when STBY is High. The soft start time is fixed at 5ms.

#### 2. Notes for PCB Layout



- (1) Place capacitors between VCC and Ground. The Schottky diode should be placed as close as possible to the IC to reduce noise and maximize efficiency.
- (2) Connect resistors between INV and Ground. Also connect the output capacitor filter at the same ground potential in order to stabilize the output voltage. (If the pattern is longer or thin, it may cause ringing or waveform distortion.)

# 3. Application Component Selection and Settings

# (1) Inductor L<sub>1</sub>

Large inductor series impedance will result in deterioration of efficiency. OCP operation greater than 1.6A may cause the inductor to overheat, possibly leading to overload or output short.

Note that the current rating for the coil should be higher than  $I_{OUT}(MAX) + \Delta I_L$ .

#### where:

IOUT(MAX): maximum load current

If you allow current flow more than maximum current rating, the coil will overload. It will cause magnetic saturation that results for efficiency deterioration. Select a coil with enough current rating which does not exceed peak current.

$$\Delta I_L = \frac{\left(V_{CC} = V_{OUT}\right)}{L_1} \times \frac{V_{OUT}}{V_{CC}} \times \frac{1}{f_{OSC}}$$

where:

L1 is the inductor value. V<sub>CC</sub> is the maximum input voltage. *V*<sub>OUT</sub> is the output voltage.  $\Delta I_L$  is the coil ripple current value. fosc is the oscillation frequency.

For better efficiency, C10-H5R (Mitsumi) is recommended. The efficiency will improve by 1% to 2%.

#### (2) Schottky Diode D1

A Schottky diode with extremely low forward voltage should be used. Selection should be based on the following guidelines regarding maximum forward current, reverse voltage, and power dissipation:

- (a) The maximum current rating is higher than the combined maximum load current and coil ripple current ( $\Delta I_L$ ).
- (b) The reverse voltage rating must be higher than the  $V_{IN}$  value.
- (c) Recommend using a diode with smaller the reverse current as possible.
- (d) In the high temperature case, the reverse current is increasing and it may cause overdrive. Power dissipation for the selected diode must be within the rated level.

The power dissipation of the diode is expressed by the following formula:

 $Pdi = I_{OUT}(MAX) \times V_F \times (1 - V_{OUT} / V_{CC})$ 

where:

IOUT(MAX) is the maximum load current.  $V_F$  is the forward voltage.  $V_{OUT}$  is the output voltage. V<sub>CC</sub> is the input voltage.

#### (3) Output Capacitor C<sub>1</sub>

A suitable output capacitor should satisfy the following formula for ESR:

 $ESR \leq \Delta V_L / \Delta I_L$ 

where:  $\Delta V_L$  is the permissible ripple voltage.  $\Delta I_L$  is the coil ripple current.

Another factor that must be considered is the permissible ripple current. Select a capacitor with sufficient margin, governed by the following formula:

$$I_{RMS} = \Delta I_L / 2\sqrt{3}$$

where:

*I<sub>RMS</sub>* is the effective value of ripple current to the output capacitor.  $\Delta I_L$  is the coil ripple current.

Use ceramic capacitor over B characteristic of temperature. Otherwise, it is possible to cause abnormal operation of IC depending on the ambient temperature or output voltage setting.

It is also possible to use AI electrolytic capacitor, but use it with sufficient margin.

# BD9870FPS

# (4) Input Capacitor C2

The input capacitor is the source of current flow to the coil via the built-in P-Channel FET when the FET is ON. When selecting the input capacitor, sufficient margin must be provided to accommodate capacitor voltage and permissible ripple current. The expression below defines the effective value of the ripple current to the input capacitor. It should be used in determining the suitability of the capacitor in providing sufficient margin for the permissible ripple current.

$$I_{RMS} = I_{OUT} \times \sqrt{\left(1 - V_{OUT} / V_{CC}\right) \times V_{OUT} / V_{CC}}$$

Where:

 $I_{RMS}$  is the effective value of the ripple current to the input capacitor.  $I_{OUT}$  is the output load current.  $V_{OUT}$  is the output voltage.  $V_{CC}$  is the input voltage.

#### (5) Capacitor C<sub>3</sub>

This capacitor is utilized to stabilize the frequency characteristics, but is seldom used. However, if the phase margin is insufficient and oscillation is likely to occur, connecting this capacitor may improve frequency stability.

### (6) Resistor R<sub>1</sub>,R<sub>2</sub>

These resistors determine the output voltage:

 $V_{OUT} = 1.0V \times (1 + R_1 / R_2)$ 

Select resistors less than  $10k\Omega$ .

#### <Recommended Components (Example)>

Inductor	L₁=10µH	: C6-K3LA (MITSUMI)
Schottky Diode	D <sub>1</sub>	: RB050LA-30 (ROHM) use when VCC is less than 30V
	D2	: RB050LA-40 (ROHM) use when VCC is greater than 30V
Capacitor	C1=10µF(25V)	: ceramic cap GRM31CB31E106KA75L(Murata)
	$C_2 = 4.7 \mu F(50V)$	: ceramic cap GRM32EB31H475KA87L(Murata)
	C <sub>3</sub> =OPEN	
<recommended corr<="" td=""><td>ponents example 2&gt;whe</td><td>n the Duty ratio of output/input voltage is less than 10%</td></recommended>	ponents example 2>whe	n the Duty ratio of output/input voltage is less than 10%
Inductor	L₁=10µH	: C6-K3LA (MITSUMI)
Schottky Diode	D <sub>1</sub>	: RB050LA-30 (ROHM) use when VCC is less than 30V
-	D <sub>2</sub>	: RB050LA-40(ROHM) use when VCC is more than 30V
Capacitor	C <sub>1</sub> =100µF(25V)	: AI electric capacitor UHD1E101MED(Nichicon)
	C <sub>2</sub> =4.7µF(50V)	: ceramic cap GRM32EB31H475KA87L(Murata)
	C <sub>3</sub> =OPEN	

#### 4. Test Circuit

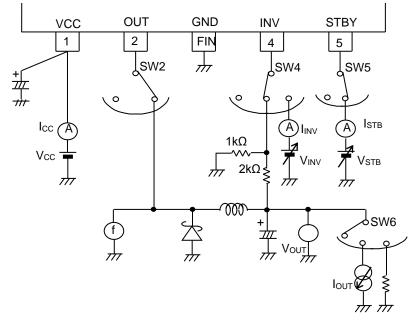


Figure 16. Input Output Measurement Circuit

# I/O Equivalent Circuit

**Power Dissipation** 

Pin 1 (VCC, GND)	Pin 2 (OUT)	Pin 4 (INV)	Pin 5 (STBY)
			STBY

Figure 17. Input Output Equivalent Circuit

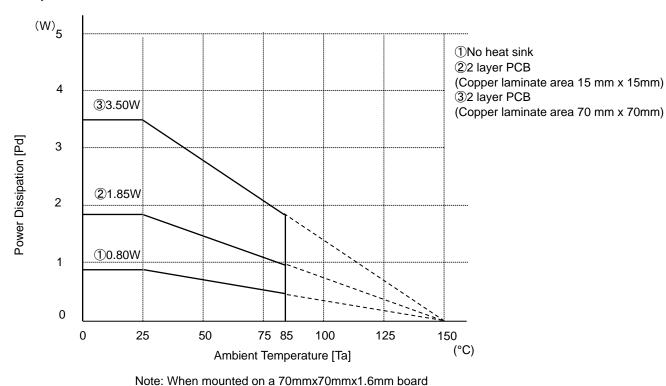


Figure 18. Power Dissipation

# **Operational Notes**

#### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

#### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

#### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

#### 6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

#### 7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

#### 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

#### 9. **Testing on Application Boards**

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

#### 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

### **Operational Notes – continued**

#### 11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

#### 12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

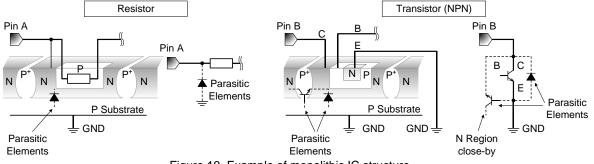


Figure 19. Example of monolithic IC structure

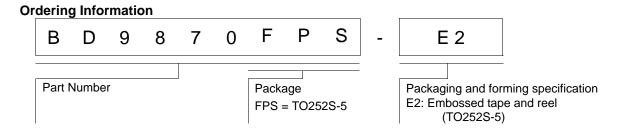
#### 13. Thermal Shutdown Circuit(TSD)

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

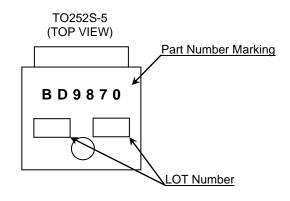
Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

#### 14. Operation

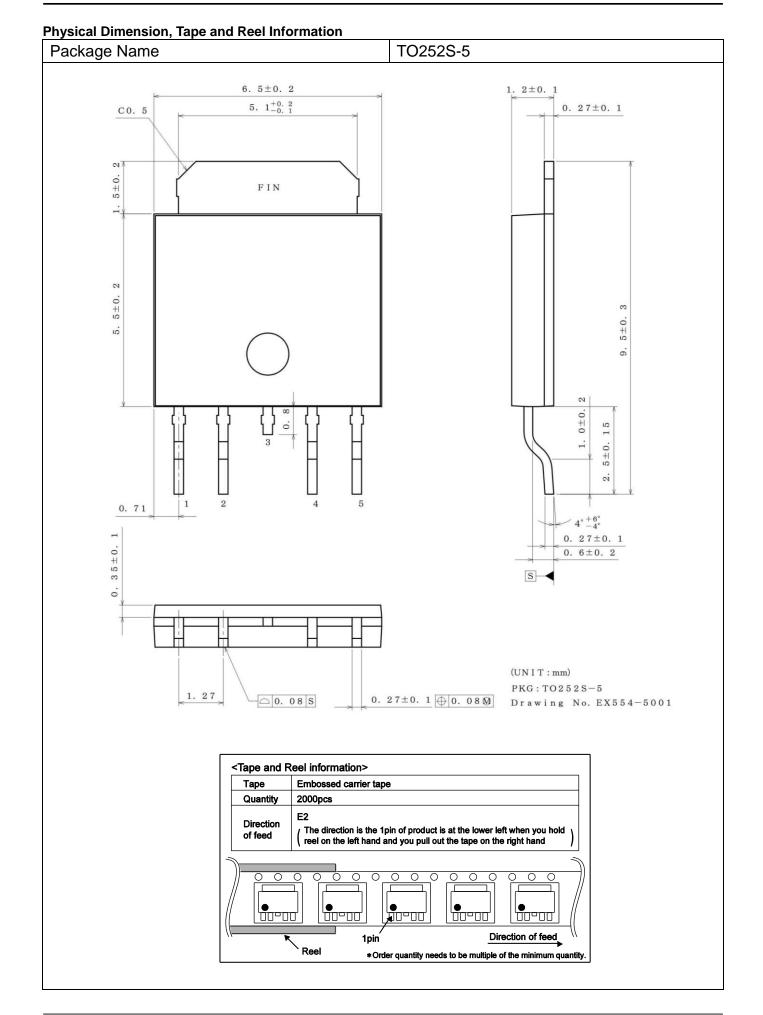
The IC will turn ON when the voltage at the STBY pin is greater than 2.0V and will switch OFF if under 0.3V. Therefore, do not input voltages between 0.3V and 2.0V. Malfunctions and/or physical damage may occur.



# **Marking Diagram**



# Datasheet



# **Revision History**

Date	Revision	Changes
05.Nov.2014	001	New Release

# Notice

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(Note1) Medical Equipment Classification of the Specific Applications
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JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSI	CLASS II b	CLASSII
CLASSⅣ	CLASSII	CLASSⅢ	CLASSI

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  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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